

CHARACTERIZATION OF PHOSPO-VANADATE GLASSY SYSTEM USING FT-IR TECHNIQUE

K. V. DESHMUKH^{*}, R. V. BARDE^a and S. A. WAGHULEY

Department of Physics, Sant Gadge Baba Amravati University, AMRAVATI – 444 602 (M.S.) INDIA ^aDept. of Engg. Physics, H.V. P. M. College of Engg. & Technology, AMRAVATI – 444601 (M.S.) INDIA

(Received : 17.02.2012; Revised : 14.03.2012; Accepted : 23.03.2012)

ABSTRACT

Phospo-Vanadate glasses have been studied intensively in the recent decades for electrical, optical and thermal properties as well as important applications in piezoelectric, ferroelectrics and non-linear optical device materials. Phospo-Vanadate base glasses are important class of conducting glasses. The glass systems ($xV_2O_5 - (100 - x)P_2O_5$) with x = 20, 40 and 50 mol % were prepared by melt-quenching approach. The glass system was characterized by FT-IR analysis. All principal bonding in V_2O_5 - P_2O_5 glasses were confirmed from FT-IR analysis.

Key words: Phospo-vanadate, FT-IR, Conducting glasses.

INTRODUCTION

The structural properties of amorphous materials are extracted from analyses of the infrared spectra measurements. IR spectra of glasses are of great importance because they provide valuable information on the atomic configurations in these materials, i.e., the extent to which added cations either enter the network of the basic glass or reside in it interstitially and the extent to which the double bond, e.g., P = O in the phosphate network, is broken can be qualitatively assessed. The addition of some addivies such as alumina, boric, lead, zinc, alkaline rare earth materials, transition metal oxides into phosphate matrix improved their chemical durability to be suitable for sealing to medium and low expansion materials¹. The electrical properties of transition metal oxide glasses formed with traditional glasses former such as phosphate, borate etc. have been studied extensive because of their interesting semiconducting properties²⁻⁵. These glasses are also interesting for their electrical switching properties .The semiconducting behavior of these transition metal oxide glasses arises from the fact that the transition metal ions exist in more than one valence state so that electrical conduction takes place by the hopping of electrons from the low valence state to the high valence state of transition metal ions. The vanadate glasses formed with the addition of traditional network formers or modifier oxides, where V_2O_5 acts as the network former, exhibit semiconducting properties due to the presence of both V^{4+} and V^{5+} ions. The electron-Phonon interaction is strong enough to form small polarons in these glasses and the electrical conduction occurs by the hopping of small polarons between V⁴⁺ and V^{5+} ions either in the adiabatic or in non-adiabatic regime⁶. However, there exist a controversy over the nature of hopping mechanism in different temperature and composition regimes⁷⁻⁹. A few structural studies

Available online at www.sadgurupublications.com

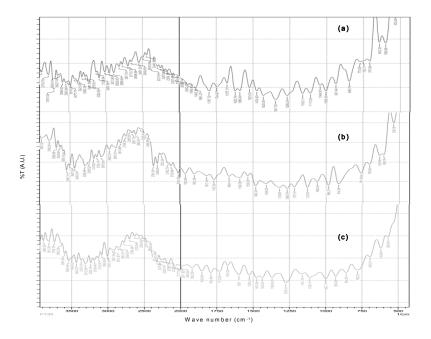
^{*}Author for correspondence; E-mail: deshmukhkv89@yahoo.com, sandeepwaghuley@sgbau.ac.in

of vanadate glasses have been reported^{10,11}. It has been observed that the structure of these glasses depends on the nature of the network former as well as the modifier. The transition metal oxide glasses are interesting because of their probable application in threshold and memory switching as well as in other application like cathode materials. These glasses show more than one valence state for the transition metal ions¹². For a variety of alkali and alkaline rare-earth phosphates, the IR spectra were very similar, indicating that the absorption bands resulted from the vibration of P–O groups¹.

In the present work, glass samples of V_2O_5 - P_2O_5 were prepared by melt-quenching method. The samples were characterized by FT-IR analysis to know the bonding in the sample.

EXPERIMENTAL

AR grade chemicals P_2O_5 , V_2O_5 , in powder form and acetone were used to prepare the V_2O_5 - P_2O_5 glasses. The powders were thoroughly mixed with proportional in glassy system ($x V_2O_5 - (100 - x) P_2O_5$) with x = 20,40 and 50 mol %) using acetone. The mixture of these chemicals was put in silica crucibles for drying in vacuum furnace for 30 min. After drying, the mixtures were transferred to a second electric furnace held at a temperature 1100 – 1200 K for 3 h. The melt was then poured in between stainless steel plates for quenching. For electrical measurements, silver paste was deposited on both sides of the glass sample and dried at 70°C. The FT-IR measurements were performed on a Perkin-Elmer 1430 Ratio Recording IR spectrophotometer, which used over the range 400 to 4000 cm⁻¹. The samples of glass weighing 10 mg each were mixed and ground with 225 mg of KBr.



RESULTS AND DISCUSSION

Fig. 1: FT-IR spectra of V₂O₅-P₂O₅ glass with mole % of (a) 20, (b) 40 and (c) 50

FT-IR spectra in the region 400-4000 cm⁻¹ of all glass compositions are shown in figure 1. The IR absorption spectra of the [x V₂O₅-(100- x) P₂O₅] glasses system, where x = 20,40 and 50 mol%. Inspection of this figure reveals that all tested glasses show a great similarity in the shape of their absorption spectra which agrees with the results reported in¹, where the IR spectra of binary phosphate glasses are essentially the same. The bands observed in this work at 1392 to 1377, 905 to 800 and 735 to 715 cm⁻¹ could be

attributed to the P=O double bond^{13,14}, the stretching symmetric and the stretching anti symmetric P–O–P ring frequency^{13,14}, respectively. The absorption of bands at 1095-1085 are assigned to the v₃ tetrahedral normal vibration of PO₄⁻³ ion¹³. All the spectra shows the water band at 1620-1630 cm⁻¹ and broad band around 3400 cm⁻¹ due to absorbed water in the powdered sample required for making pellets. The band near the 1020 cm⁻¹ assigned to the stretching vibration of the isolated V=O vanadyl group in VO₅ trigonal bipyramid is observed only in the spectra for the glass composition for higher V₂O₅. This band becomes weaker with the decrease of V₂O₅. The band in the 915-920 cm⁻¹ range is assigned to the vibrations of the free VO₂- groups of the VO₄-polyhedra⁶.

It is well known that the phosphate network is built up from corner-sharing PO₄ tetrahedral units. According to the number of bridging oxygen the tetrahedral units are usually classified according to their connectivity (Q^n), where n (n = 0, 1, 2, 3) is the number of bridging oxygen's per PO₄ tetrahedron. Consequently, the infra red response of the phosphate network can roughly be divided into three spectral regions related to activity of: (i) non bridging oxygen modes, 940-1380 cm⁻¹; (ii) bridging oxygen modes, 700-900 cm⁻¹; (iii) deformation modes, 500 cm⁻¹, respectively .The relevant part of IR spectra the IR frequency around 720-780 cm⁻¹, assigned to symmetric stretch mode of P-O-P linkage. The IR frequency around 880-900 cm⁻¹, assigned to asymmetric stretching mode of P-O-P linkage.

CONCLUSION

The glass samples were prepared by melt quenching method, which is very easy and low cost approach of preparation of conducting glasses. The FT-IR study of glasses revels that the IR spectra of phosphate are similar in shape. They are found to be dependent not only on the nature of anions but also the type of oxide added.

ACKNOWLEDGEMENT

Authors are thankful to Head, Department of Physics Sant Gadge Baba Amravati University, Amravati for providing necessary facilities.

REFERENCES

- 1. A. H. Khafagy, J. Phys. Stat. Sol., 186(1), 105-114 (2001).
- 2. B. Peng, Z. Fan, X. Qui, L. Jiang, G. H. Tang, H. D. Ford and W. Huang, Adv. Mater., 17, 857 (2005).
- 3. A. Mekki, G. D. Khattak and L. E. Wenger, J. Non-Cryst. Solids, **330**, 156-167 (2003).
- 4. M. Chinkhota, P. S. Fodor, G. D. Khattak and L. E. Wenger, J. Appl. Phys., **91**, 8269-8272 (2002).
- 5. C. B. Rao, K. V. Ramesh and D. L. Sastry, Physica B, 382, 81 (2006).
- 6. Aloka Ghosh, S. Bhattacharya, D. P. Bhattacharya and A. Ghosh, J. Phys. Condens. Matter, **19**, 106222 (2007).
- 7. S. Sen and A. Ghosh, J. Appl. Phys., 87, 3355 (2000).
- 8. S. Smdhu, S. Sanghi, A. Agarwal, Sonam, V. P. Seth and N. Kishor, Physica B, 365, 65 (2005) .
- 9. S. Bhattacharya and A. Ghosh, Phys. Rev., **B72**, 104203 (2002).
- 10. S. Sen and A. Ghosh, J. Mater. Res., 12, 195 (2000).
- 11. G. D. Khattak, N. Tatet and L. E. Wenger, Phys. Rev., **B** 72, 104203 (2005).

- 12. D. K. Modak, U. K. Mandal, M. Sadhukhan and B. K. Chaudhuri, J. Mater. Sci., 36, 2539-2545 (2001).
- 13. P. Subbalakshmi, N. Veeraiav, J. Mater. Letters, 56, 880 (2002).
- 14. P. Boolchand, D. G. Georgiev, F. Wang, T.Qu, L. Cai and S. Chakravarty, Comptes Rendus. Chim., 5, 713 (2002).